

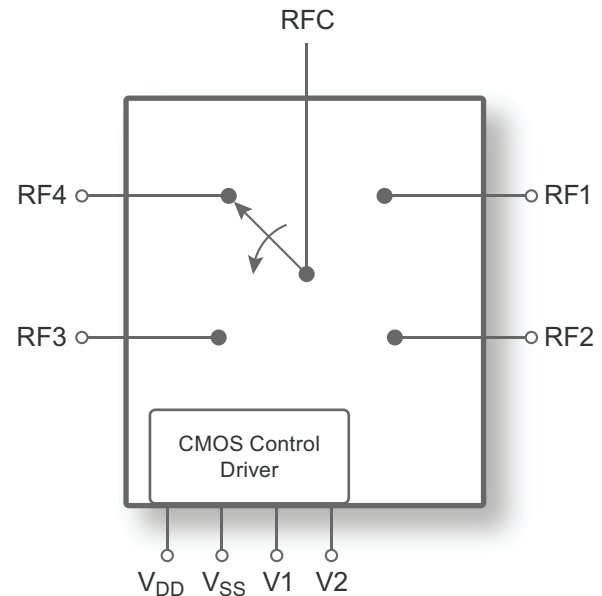
Features

- Wideband support up to 67 GHz
- Low insertion loss of 2.6 dB @ 45 GHz
- Fast switching time of 75 ns
- High input P1dB of 33.5 dBm
- Low return loss of 20 dB @ 60 GHz
- -40 °C to +105 °C operating temperature support
- Package: Flip-chip die

Applications

- Test and measurement (T&M)
- 5G mmWave
- Microwave backhaul
- Radar
- Satellite communications

Figure 1 ■ PE42545 Functional Diagram



Product Description

The PE42545 is a HaRP™ technology-enhanced reflective SP4T RF switch die that supports a wide frequency range from 9 kHz to 67 GHz. It delivers low insertion loss, fast switching time and high isolation performance, making this device ideal for test and measurement (T&M), 5G mmWave, microwave backhaul, radar and satellite communication applications. No blocking capacitors are required if DC voltage is not present on the RF ports.

The PE42545 is manufactured on pSemi's UltraCMOS® process, a patented variation of silicon-on-insulator (SOI) technology.

Ordering Information

Table 1 lists the available ordering codes for the PE42545 as well as available shipping methods.

Table 1 ■ Order Codes for PE42545

Order Codes	Description	Packaging	Shipping Method
PE42545A-Z	PE42545 SP4T RF switch	Die on tape and reel	3000 die/T&R
EK42545-01	PE42545 SP4T RF switch probe EVK	Evaluation Kit	1/Box
EK42545-88	PE42545 SP4T RF switch connectorized EVK	Evaluation Kit	1/Box

Document Categories

Advance Information

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. pSemi reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

The datasheet contains final data. In the event pSemi decides to change the specifications, pSemi will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

Product Brief

This document contains a shortened version of the datasheet. For the full datasheet, contact sales@psemi.com.

Sales Contact

For additional information, contact Sales at sales@psemi.com.

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